

■ ABSOLUTE MAXIMUM RATINGS ($T_C=25^\circ\text{C}$, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	650	V
Gate-Source Voltage		V_{GSS}	± 30	V
Drain Current	Continuous ($T_C=25^\circ\text{C}$)	I_D	16 (Note 2)	A
	Pulsed (Note 3)	I_{DM}	64 (Note 2)	A
Avalanche Current (Note 3)		I_{AR}	16	A
Avalanche Energy	Single Pulsed (Note 4)	E_{AS}	780	mJ
	Repetitive (Note 5)	E_{AR}	20	mJ
Peak Diode Recovery dv/dt (Note 5)		dv/dt	4.5	V/ns
Power Dissipation ($T_C=25^\circ\text{C}$)		P_D	62	W
Linear Derating Factor above $T_C=25^\circ\text{C}$			0.49	W/ $^\circ\text{C}$
Junction Temperature		T_J	+150	$^\circ\text{C}$
Storage Temperature		T_{STG}	-55~+150	$^\circ\text{C}$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Drain current limited by maximum junction temperature
3. Repetitive Rating: Pulse width limited by maximum junction temperature
4. $L = 6.1\text{mH}$, $I_{AS} = 16\text{A}$, $V_{DD} = 50\text{V}$, $R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$
5. $I_{SD} \leq 16\text{A}$, $di/dt \leq 200\text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, Starting $T_J = 25^\circ\text{C}$

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ_{JA}	62.5	$^\circ\text{C}/\text{W}$
Junction to Case	θ_{JC}	2.0	$^\circ\text{C}/\text{W}$

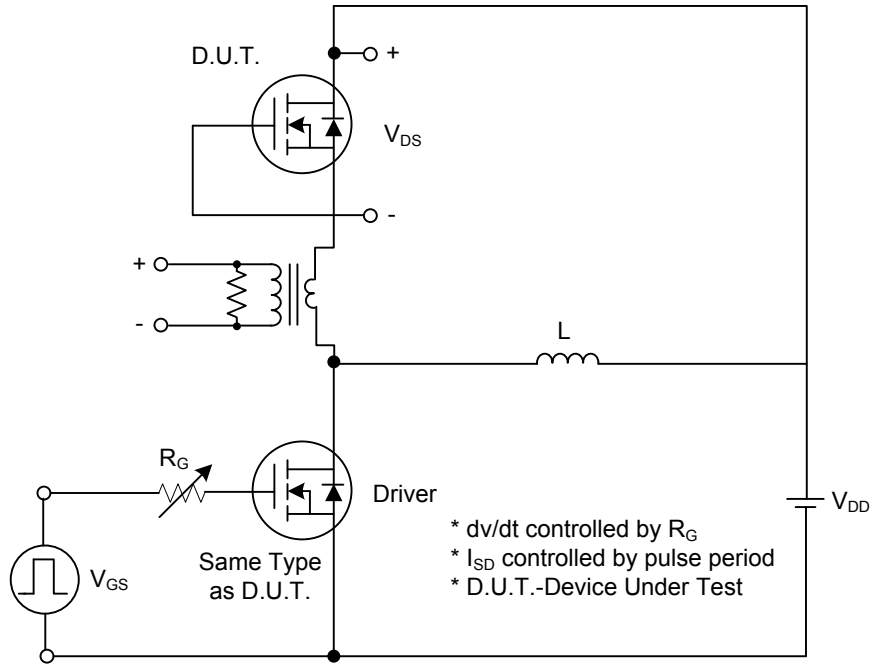
■ ELECTRICAL CHARACTERISTICS ($T_C=25^\circ\text{C}$, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		BV_{DSS}	$I_D=250\mu\text{A}$, $V_{GS}=0\text{V}$	650			V
Drain-Source Leakage Current		I_{DSS}	$V_{DS}=650\text{V}$, $V_{GS}=0\text{V}$			1	μA
			$V_{DS}=520\text{V}$, $V_{GS}=0\text{V}$, $T_C=125^\circ\text{C}$			10	μA
Gate- Source Leakage Current	Forward	I_{GSS}	$V_{GS}=+30\text{V}$, $V_{DS}=0\text{V}$			+100	nA
	Reverse		$V_{GS}=-30\text{V}$, $V_{DS}=0\text{V}$			-100	nA
ON CHARACTERISTICS							
Gate Threshold Voltage		$V_{GS(TH)}$	$V_{DS}=V_{GS}$, $I_D=250\mu\text{A}$	2.0		4.0	V
Static Drain-Source On-State Resistance		$R_{DS(ON)}$	$V_{GS}=10\text{V}$, $I_D=8\text{A}$		0.35	0.54	Ω
DYNAMIC PARAMETERS							
Input Capacitance		C_{ISS}	$V_{GS}=0\text{V}$, $V_{DS}=25\text{V}$, $f=1.0\text{MHz}$		1078		pF
Output Capacitance		C_{OSS}			225		pF
Reverse Transfer Capacitance		C_{RSS}			10		pF
SWITCHING PARAMETERS							
Turn-ON Delay Time		$t_{D(ON)}$	$V_{DS}=30\text{V}$, $I_D=0.5\text{A}$, $R_G=25\Omega$ (Note 1, 2)		112		ns
Rise Time		t_R			186		ns
Turn-OFF Delay Time		$t_{D(OFF)}$			335		ns
Fall-Time		t_F			186		ns
Total Gate Charge		Q_G	$V_{GS}=10\text{V}$, $V_{DS}=50\text{V}$, $I_D=1.3\text{A}$ (Note 1, 2)		57		nC
Gate to Source Charge		Q_{GS}			15.4		nC
Gate to Drain Charge		Q_{GD}			15.8		nC
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS							
Maximum Body-Diode Continuous Current		I_S				16	A
Maximum Body-Diode Pulsed Current		I_{SM}				64	A
Drain-Source Diode Forward Voltage		V_{SD}	$I_S=16\text{A}$, $V_{GS}=0\text{V}$			1.4	V

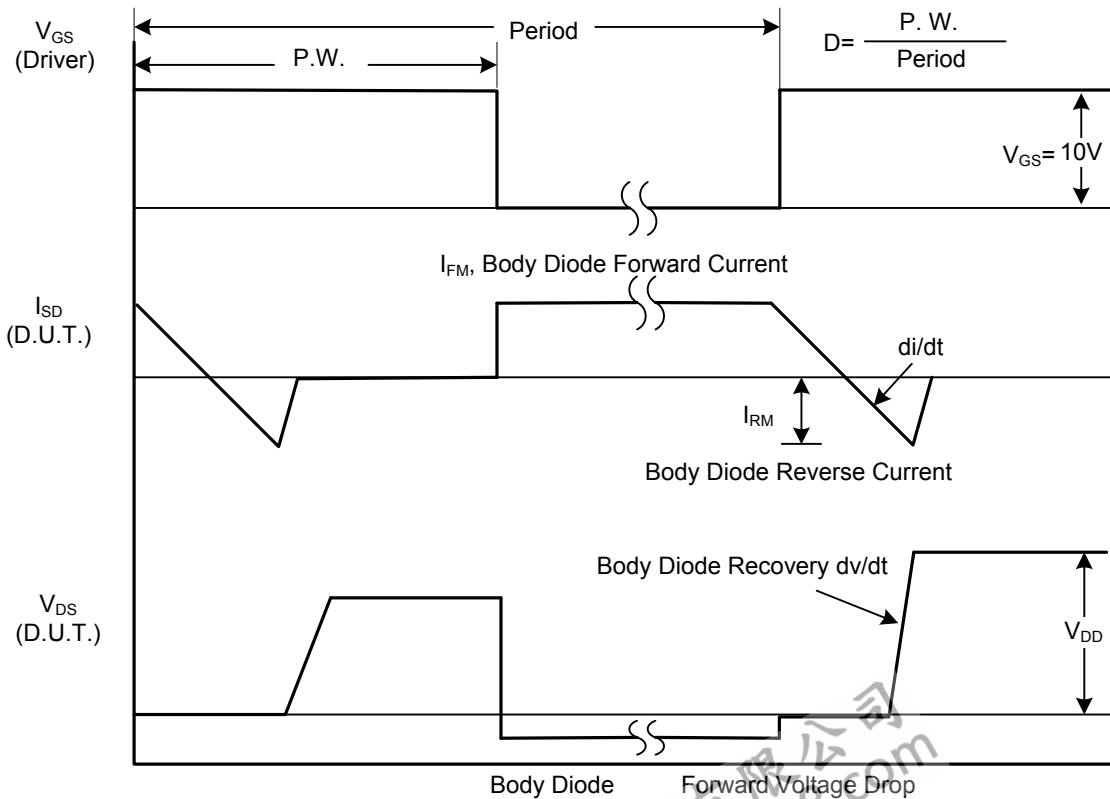
Notes: 1. Pulse Test: Pulse width $\leq 300\mu\text{s}$, Duty cycle $\leq 2\%$

2. Essentially independent of operating temperature

TEST CIRCUITS AND WAVEFORMS

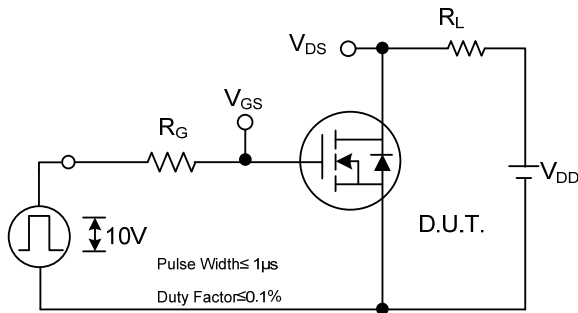


Peak Diode Recovery dv/dt Test Circuit

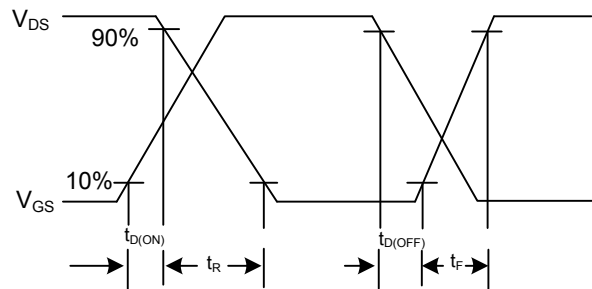


Peak Diode Recovery dv/dt Waveforms

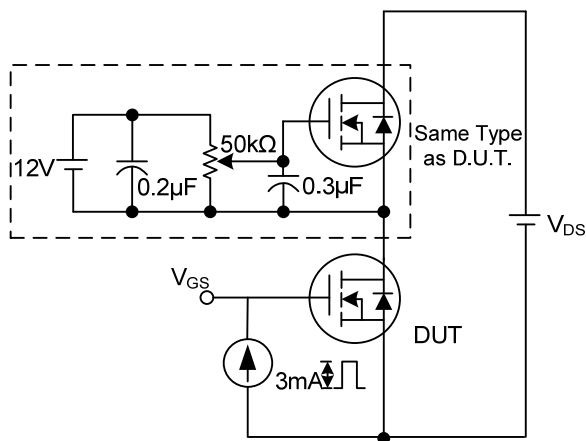
TEST CIRCUITS AND WAVEFORMS (Cont.)



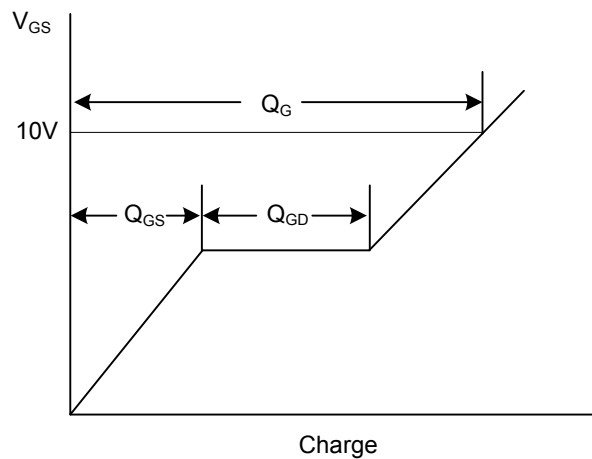
Switching Test Circuit



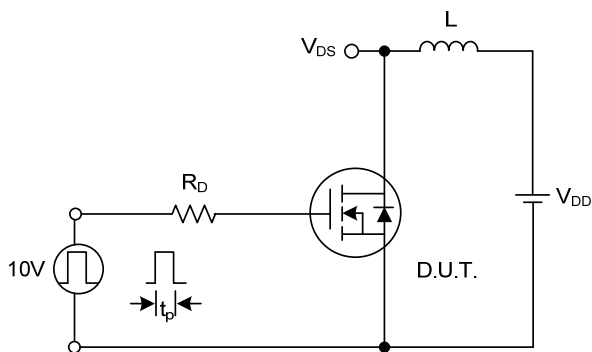
Switching Waveforms



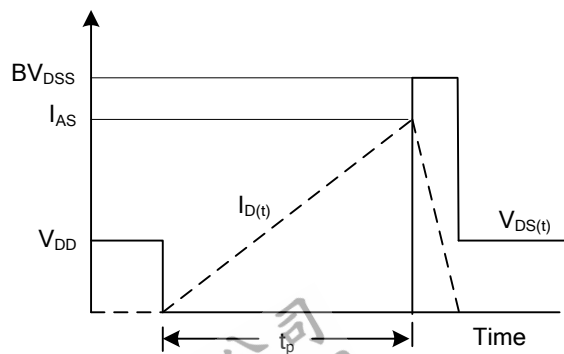
Gate Charge Test Circuit



Gate Charge Waveform



Unclamped Inductive Switching Test Circuit



Unclamped Inductive Switching Waveforms

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